





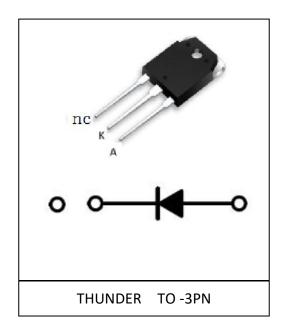
Thunder High Power Products

FRD Ultrafast Soft Recovery Diode, 80A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary		
VR	600 V	
lf(AV)	80A	
trr	32ns	



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	80	
Single pulse forward current	IFSM	Tc =25°C	640	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	160	
Operating junction	Tj		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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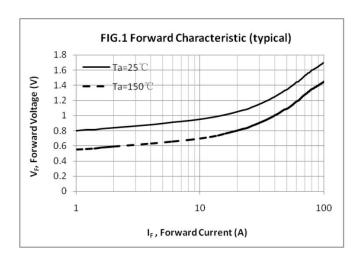
Electrical characteristics (Ta=25°C unless otherwise specified)

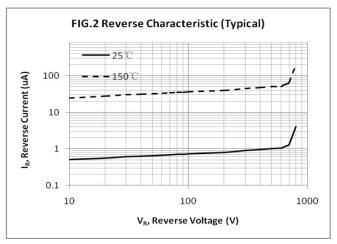
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage Blocking voltage	VBR, V _R	Ir=100µA	600			
Forward voltage (Per Diode)	VF	Ir=80A		1.45	1.80	V
		IF=80A, Tj =125°C		1.35	1.70	
Reverse leakage current(Per Diode)		Vr= Vrrm			50	
	lR	Tj=150°C, V _R =600V			500	μ Α
Reverse recovery time(Per Diode)		I _F =0.5A, I _R =1A, I _{RR} =0.25A		43	55	nc
	trr	I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		32	40	ns

Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	R _{θJC}	0.7	°C/W

Electrical performance (typical)



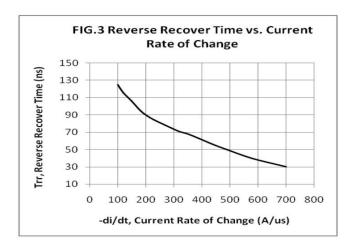


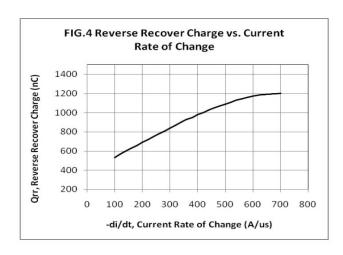
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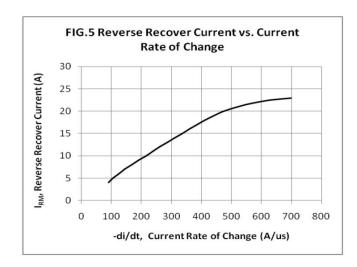


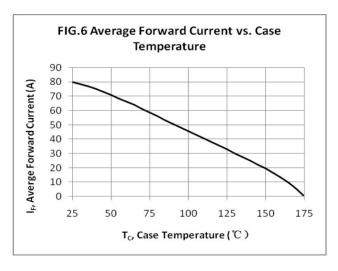


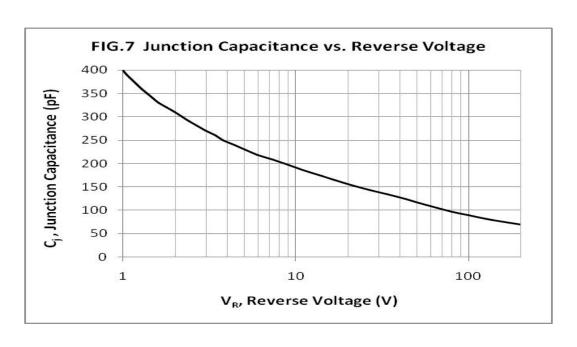












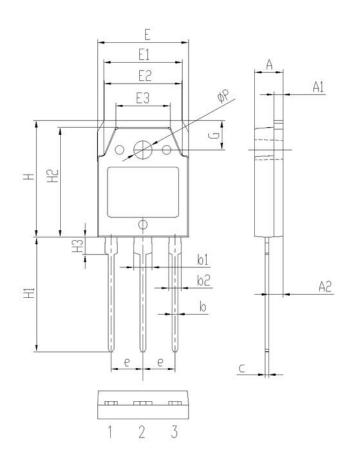
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Package Information

TO-3PN PACKAGE



Cumbal	Dimensions(millimeters)		
Symbol	Min.	Max.	
Α	4.60	5.00	
A1	1.30	1.70	
A2	2.20	2.60	
b	0.80	1.20	
b1	2.90	3.30	
b2	1.90	2.30	
С	0.40	0.80	
е	5.25	5.65	
Е	15.3	15.7	
E1	13.2	13.6	
E2	13.1	13.5	
E3	9.10	9.50	
Н	19.7	20.1	
H1	19.1	20.1	
H2	18.3	18.7	
Н3	2.80	3.20	
G	4.80	5.20	
ΦР	3.00	3.40	

Notice

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